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1. GENSETS: GENERators for Small Electrical and Thermal Systems (GENSETS)

Release Date: 07-16-2015 Open Date: 07-16-2015 Due Date: 08-17-2015 Close Date: 08-17-2015

PLEASE NOTE: A prior Letter of Intent is not required for this specific FOA from DOE-ARPA-E. SUMMARY The GENSETS Program – GENERators for Small Electrical and Thermal Systems – seeks to fund the development of potentially disruptive generator technologies that will enable widespread deployment of residential Combined Heat and Power (CHP) systems. Here, CHP is defined as the distributed generat ...

SBIRSTTR Department of Energy ARPA-E

2. 1: MOSAIC STTR

Release Date: 12-08-2014 Open Date: 12-08-2014 Due Date: 01-22-2015 Close Date: 01-22-2015

The MOSAIC (Micro-scale Optimized Solar-cell Arrays with Integrated Concentration) Program will fund potentially disruptive technologies and related system concepts to achieve new performance and cost benchmarks for solar-electric generation from photovoltaics (PV). Specifically, MOSAIC will develop novel concepts that integrate arrays of high-performan ...

STTR Department of Energy

3. Strategies for Wide-Bandgap, Inexpensive Transistors for Controlling High Efficiency Systems (SWITCHES) (STTR)

Release Date: 06-11-2013 Open Date: 06-11-2013 Due Date: 07-19-2013 Close Date: 07-19-2013

This program seeks to fund transformational advances in wide bandgap (WBG) materials, device fabrication, and device architectures. The goal of this program is to enable the development of high voltage (1200V+), high current (100A) single die power semiconductor devices that, upon ultimately reaching scale, would have the potential to reach functional cost parity with silicon power transistors whi ...

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